Features

- **EE Programmable 262,144 x 1-, 524,288 x 1-, 1,048,576 x 1-, 2,097,152 x 1-, and 4,194,304 x 1-bit Serial Memories Designed to Store Configuration Programs for Field Programmable Gate Arrays (FPGAs)**
- **Available as a 3.3V (±10%) Commercial and Industrial Version**
- **Simple Interface to SRAM FPGAs**
- **Pin Compatible with Xilinx® XC17SXXXA and XC17SXXXXL PROMs**
- **Compatible with Xilinx Spartan®-II, Spartan-IIE and Spartan XL FPGAs in Master Serial Mode**
- **Very Low-power CMOS EEPROM Process**
- **Available in 8-lead PDIP, 8-lead SOIC, 20-lead SOIC and 44-lead TQFP Packages for a Specific Density**
- **Low-power Standby Mode**
- **High-reliability**
  - **Endurance: Minimum 10 Write Cycles**
  - **Data Retention: 20 Years at 85°C**

Description

The AT17N series FPGA Configuration EEPROM (Configurators) provide an easy-to-use, cost-effective configuration memory for Field Programmable Gate Arrays. The AT17N series device is packaged in the 8-lead LAP, 8-lead PDIP, 8-lead SOIC, 20-lead SOIC and 44-lead TQFP, see Table 1. The AT17N series Configurators uses a simple serial-access procedure to configure one or more FPGA devices.

The AT17N series configurators can be programmed with industry-standard programmers, Atmel's ATDH2200E Programming Kit or Atmel's ATDH2225 ISP Cable and factory programming.

Table 1. AT17N Series Packages

Package	AT17N256	AT17N512/ AT17N010	AT17N002	AT17N040
8-lead PDIP	Yes	Yes	–	–
8-lead SOIC	Yes	–	–	–
20-lead SOIC	Yes	Yes	Yes	–
44-lead TQFP	–	–	Yes	Yes

FPGA Configuration Memory

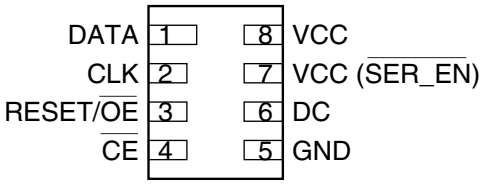
AT17N256
AT17N512
AT17N010
AT17N002
AT17N040

3.3V System Support

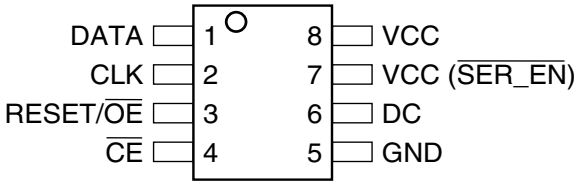
3020B–CNFG–03/06

Pin Configuration

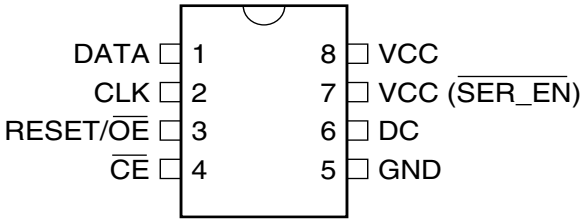
8-lead LAP



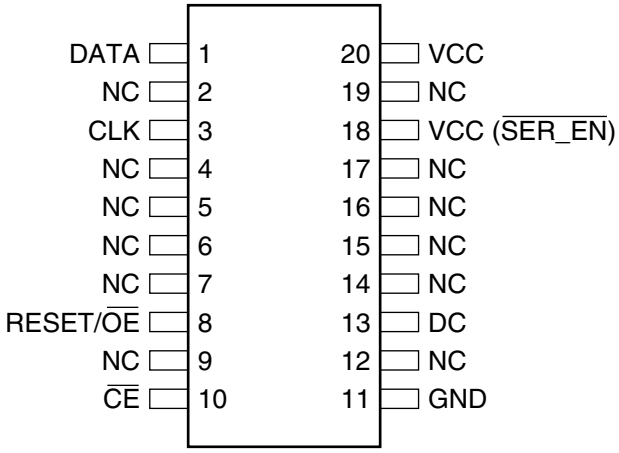
8-lead SOIC



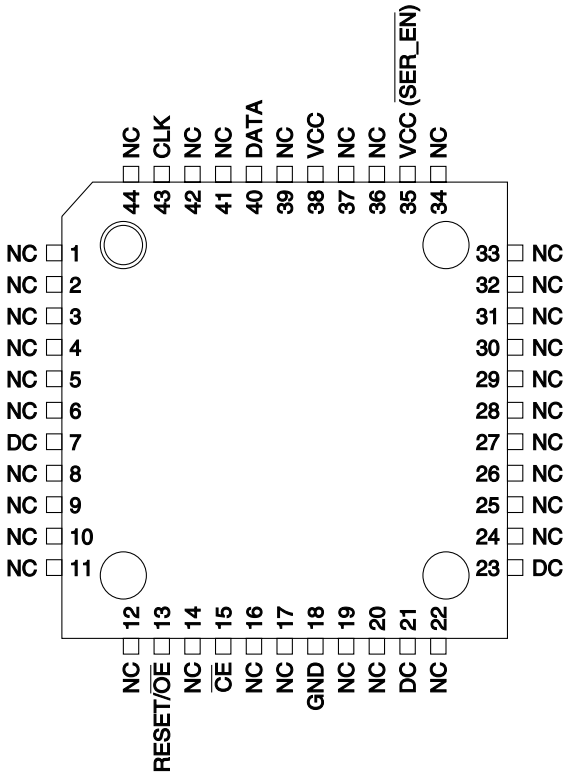
8-lead PDIP



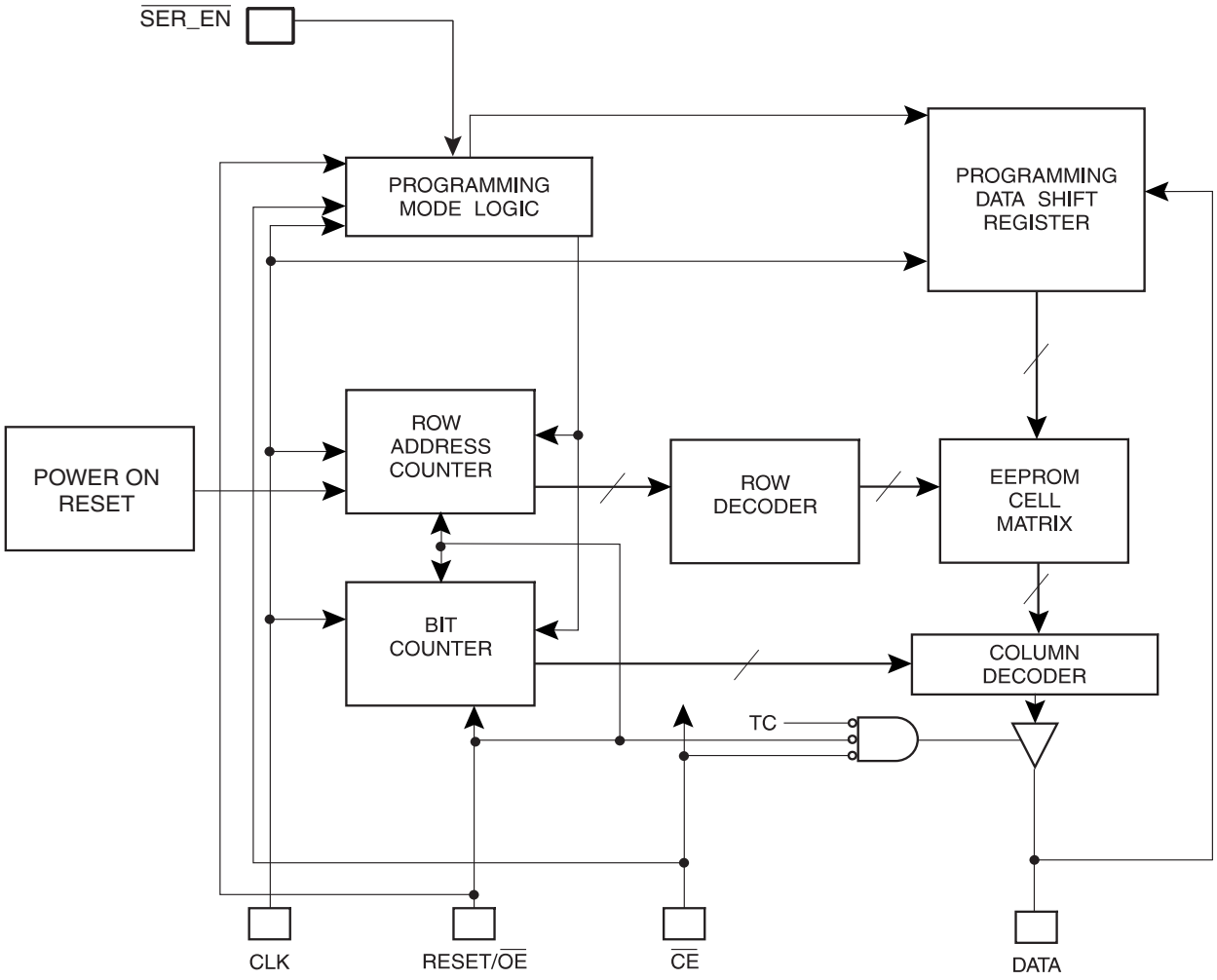
20-lead SOIC



44 TQFP


NC 1
NC 2
NC 3
NC 4
NC 5
NC 6
DC 7
NC 8
NC 9
NC 10
NC 11
12 NC
13 RESET/OE
14 NC
15 CE
16 NC
17 NC
18 GND
19 NC
20 NC
21 DC
22 NC
23 DC
24 NC
25 NC
26 NC
27 NC
28 NC
29 NC
30 NC
31 NC
32 NC
33 NC
34 NC
35 VCC (SER_EN)
36 NC
37 NC
38 VCC
39 NC
40 DATA
41 NC
42 NC
43 CLK
44 NC

Block Diagram



Device Description

The control signals for the configuration EEPROM ($\overline{CE}$, RESET/$\overline{OE}$ and CCLK) interface directly with the FPGA device control signals. All FPGA devices can control the entire configuration process and retrieve data from the configuration EEPROM without requiring an external intelligent controller.

The configuration EEPROM RESET/$\overline{OE}$ and $\overline{CE}$ pins control the tri-state buffer on the DATA output pin and enable the address counter. When RESET/$\overline{OE}$ is driven High, the configuration EEPROM resets its address counter and tri-states its DATA pin. The $\overline{CE}$ pin also controls the output of the AT17N series configurator. If $\overline{CE}$ is held High after the RESET/$\overline{OE}$ reset pulse, the counter is disabled and the DATA output pin is tri-stated. When $\overline{OE}$ is subsequently driven Low, the counter and the DATA output pin are enabled. When RESET/$\overline{OE}$ is driven High again, the address counter is reset and the DATA output pin is tri-stated, regardless of the state of $\overline{CE}$. Upon power-up, the address counter is automatically reset.

Pin Description

Name	I/O	AT17N256		AT17N512/ AT17N010		AT17N002			AT17N040
		8 DIP/ SOIC	20 SOIC	8 DIP/ LAP	20 SOIC	8 LAP	20 SOIC	44 TQFP	44 TQFP
DATA	I/O	1	1	1	1	1	1	40	40
CLK	I	2	3	2	3	2	3	43	43
RESET/$\overline{OE}$	I	3	8	3	8	3	8	13	13
$\overline{CE}$	I	4	10	4	10	4	10	15	15
GND		5	11	5	11	5	11	18	18
DC	O	6	13	6	13	6	13	21	21
DC	O	–	–	–	–	–	–	23	23
VCC($\overline{SER\_EN}$)	I	7	18	7	18	7	18	35	35
V_{CC}		8	20	8	20	8	20	38	38

DATA Three-state DATA output for configuration. Open-collector bi-directional pin for programming.

CLK Clock input. Used to increment the internal address and bit counter for reading and programming.

RESET/$\overline{OE}$ Output Enable (active High) and RESET (active Low) when $\overline{SER\_EN}$ is High. A Low level on $\overline{RESET}$/OE resets both the address and bit counters. A High level (with $\overline{CE}$ Low) enables the data output driver. The logic polarity of this input is programmable as either RESET/$\overline{OE}$ or $\overline{RESET}$/OE. For most applications, RESET should be programmed active Low. This document describes the pin as $\overline{RESET}$/OE.

$\overline{CE}$ Chip Enable input (active Low). A Low level (with OE High) allows CLK to increment the address counter and enables the data output driver. A High level on $\overline{CE}$ disables both the address and bit counters and forces the device into a low-power standby mode. Note that this pin will *not* enable/disable the device in the Two-Wire Serial Programming mode ($\overline{SER\_EN}$ Low).

GND Ground pin. A 0.2 µF decoupling capacitor between V_{CC} and GND is recommended.

VCC($\overline{SER\_EN}$) Serial enable must be held High during FPGA loading operations. Bringing $\overline{SER\_EN}$ Low enables the Two-Wire Serial Programming Mode. For non-ISP applications, $\overline{SER\_EN}$ should be tied to V_{CC}.

V_{CC} 3.3V (±10%) Commercial and Industrial power supply pin.

NC NC pins are No Connect pins, which are not internally bonded out to the die.

DC DC pins are No Connect pins internally connected to the die. It is not recommended to connect these pins to any external signal.

FPGA Master Serial Mode Summary

The I/O and logic functions of any SRAM-based FPGA are established by a configuration program. The program is loaded either automatically upon power-up, or on command, depending on the state of the FPGA mode pins. In Master mode, the FPGA automatically loads the configuration program from an external memory. The AT17N Serial Configuration EEPROM has been designed for compatibility with the Master Serial mode.

This document discusses the master serial mode configuration of Atmel AT17N series configuration memories, pin compatible with Spartan-II, Spartan-IIE and Spartan XL OTP PROMs.

Control of Configuration

Most connections between the FPGA device and the AT17N Serial EEPROM are simple and self-explanatory.

- The DATA output of the AT17N series configurator drives DIN of the FPGA devices.
- The master FPGA CCLK output drives the CLK input of the AT17N series configurator.
- $\overline{\text{SER\_EN}}$ must be connected to V_{CC} (except during ISP).
- The $\overline{\text{CE}}$ and OE/$\overline{\text{Reset}}$ are driven by the FPGA to enable output data buffer of the EEPROM.

Programming Mode

The programming mode is entered by bringing $\overline{\text{SER\_EN}}$ Low. In this mode the chip can be programmed by the Two-Wire serial bus. The programming is done at V_{CC} supply only. Programming super voltages are generated inside the chip.

Standby Mode

The AT17N series configurators enter a low-power standby mode whenever $\overline{\text{CE}}$ is asserted High. In this mode, the AT17N256 configurator consumes less than 50 µA of current at 3.3V (100 µA for the AT17N512/010 and 200 µA for the AT17N002/040).

Absolute Maximum Ratings*

Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Voltage on Any Pin with Respect to Ground	-0.1V to V_{CC} +0.5V
Supply Voltage (V_{CC})	3.0V to +3.6V
Maximum Soldering Temp. (10 sec. @ 1/16 in.)	260°C
ESD (R_{ZAP} = 1.5K, C_{ZAP} = 100 pF)	2000V

*NOTICE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those listed under operating conditions is not implied. Exposure to Absolute Maximum Rating conditions for extended periods of time may affect device reliability.

Operating Conditions

Symbol	Description		3.3V Min	3.3V Max	Units
V_{CC}	Commercial	Supply voltage relative to GND -0°C to +70°C	3.0	3.6	V
	Industrial	Supply voltage relative to GND -40°C to +85°C	3.0	3.6	V

DC Characteristics

V_{CC} = 3.3V ± 10%

Symbol	Description		AT17N256 Min	AT17N256 Max	AT17N512/ AT17N010 Min	AT17N512/ AT17N010 Max	AT17N002/ AT17N040 Min	AT17N002/ AT17N040 Max	Units
V_{IH}	High-level Input Voltage		2.0	V_{CC}	2.0	V_{CC}	2.0	V_{CC}	V
V_{IL}	Low-level Input Voltage		0	0.8	0	0.8	0	0.8	V
V_{OH}	High-level Output Voltage (I_{OH} = -2.5 mA)		2.4		2.4		2.4		V
V_{OL}	Low-level Output Voltage (I_{OL} = +3 mA)	Commercial		0.4		0.4		0.4	V
V_{OH}	High-level Output Voltage (I_{OH} = -2 mA)		2.4		2.4		2.4		V
V_{OL}	Low-level Output Voltage (I_{OL} = +3 mA)	Industrial		0.4		0.4		0.4	V
I_{CCA}	Supply Current, Active Mode			5		5		5	mA
I_L	Input or Output Leakage Current (V_{IN} = V_{CC} or GND)		-10	10	-10	10	-10	10	µA
I_{CCS}	Supply Current, Standby Mode	Commercial		50		100		150	µA
		Industrial		100		100		150	µA

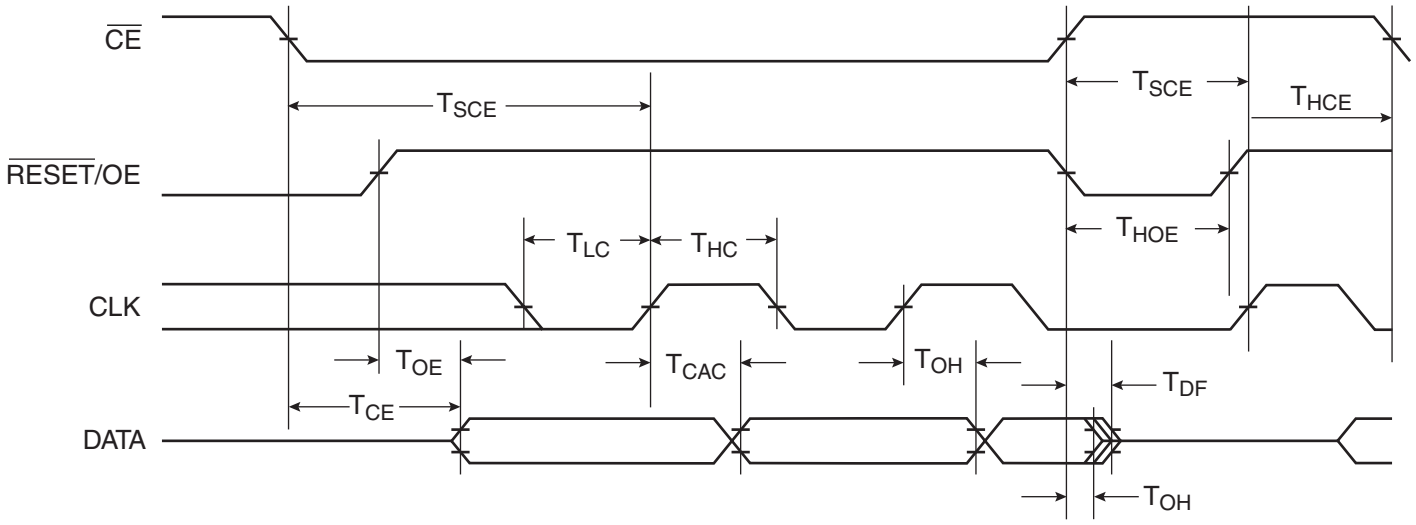
AC Characteristics

V_{CC} = 3.3V ± 10%

Symbol	Description	AT17N256 Commercial Min	AT17N256 Commercial Max	AT17N256 Industrial Min	AT17N256 Industrial Max	AT17N512/010/002/040 Commercial Min	AT17N512/010/002/040 Commercial Max	AT17N512/010/002/040 Industrial Min	AT17N512/010/002/040 Industrial Max	Units
T_{OE}[1]	OE to Data Delay		50		55		50		55	ns
T_{CE}[1]	$\overline{CE}$ to Data Delay		60		60		55		60	ns
T_{CAC}[1]	CLK to Data Delay		75		80		55		60	ns
T_{OH}	Data Hold from $\overline{CE}$, OE, or CLK	0		0		0		0		ns
T_{DF}[2]	$\overline{CE}$ or OE to Data Float Delay		55		55		50		50	ns
T_{LC}	CLK Low Time	25		25		25		25		ns
T_{HC}	CLK High Time	25		25		25		25		ns
T_{SCE}	$\overline{CE}$ Setup Time to CLK (to guarantee proper counting)	35		60		30		35		ns
T_{HCE}	$\overline{CE}$ Hold Time from CLK (to guarantee proper counting)	0		0		0		0		ns
T_{HOE}	OE High Time (guarantees counter is reset)	25		25		25		25		ns
F_{MAX}	Maximum Clock Frequency		10		10		15		10	MHz

Notes: 1. AC test lead = 50 pF.
2. Float delays are measured with 5 pF AC loads. Transition is measured ± 200 mV from steady-state active levels.

AC Characteristics

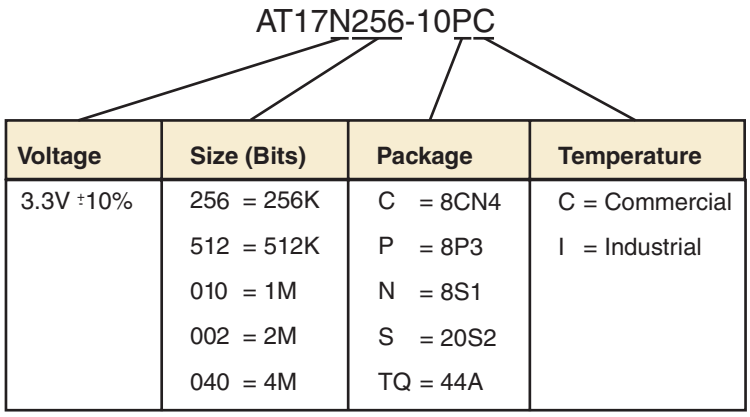


Thermal Resistance Coefficients[1]

Package Type			AT17N256	AT17N512/ AT17N010	AT17N002	AT17N040
8CN4	Leadless Array Package (LAP)	θ_{JC} [°C/W]	–	45	45	–
		θ_{JA} [°C/W][2]	–	135.71	159.60	–
8P3	Plastic Dual Inline Package (PDIP)	θ_{JC} [°C/W]	37	37	–	–
		θ_{JA} [°C/W][2]	107	107	–	–
8S1	Plastic Gull Wing Small Outline (SOIC)	θ_{JC} [°C/W]	45	–	–	–
		θ_{JA} [°C/W][2]	150	–	–	–
20S2	Plastic Gull Wing Small Outline (SOIC)	θ_{JC} [°C/W]				–
		θ_{JA} [°C/W][2]				–
44A	Thin Plastic Quad Flat Package (TQFP)	θ_{JC} [°C/W]	–	–	17	17
		θ_{JA} [°C/W][2]	–	–	62	62

Notes: 1. For more information refer to the “Thermal Characteristics of Atmel’s Packages”, available on the Atmel web site.
2. Airflow = 0 ft/min.

Figure 1. Ordering Code



Package Type	
8CN4	8-lead, 6 mm x 6 mm x 1 mm, Leadless Array Package (LAP) – Pin-compatible with 8-lead SOIC/VOID Packages
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
20S2	20-lead, 0.300" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
44A	44-lead, Thin (1.0 mm) Plastic Quad Flat Package Carrier (TQFP)

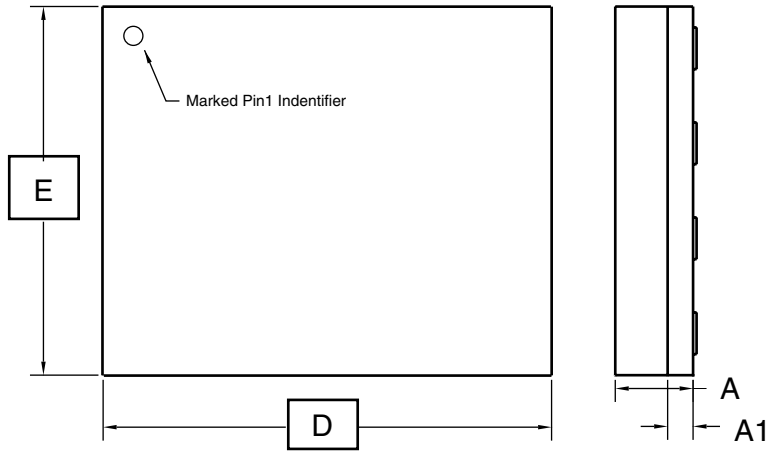
Ordering Information

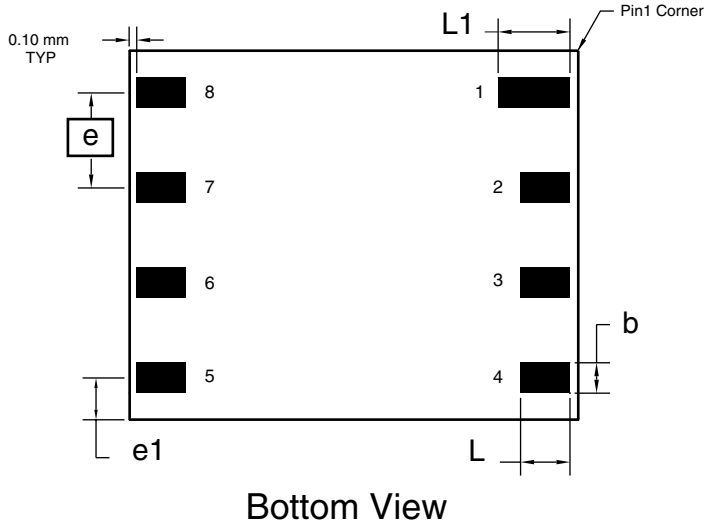
Memory Size	Ordering Code	Package	Operation Range
256-Kbit	AT17N256-10PC	8P3	Commercial (0°C to 70°C)
	AT17N256-10NC	8S1	
	AT17N256-10SC	20S2	
	AT17N256-10PI	8P3	Industrial (-40°C to 85°C)
	AT17N256-10NI	8S1	
	AT17N256-10SI	20S2	
512-Kbit	AT17N512-10CC	8CN4	Commercial (0°C to 70°C)
	AT17N512-10PC	8P3	
	AT17N512-10SC	20S2	
	AT17N512-10CI	8CN4	Industrial (-40°C to 85°C)
	AT17N512-10PI	8P3	
	AT17N512-10SI	20S2	
1-Mbit	AT17N010-10CC	8CN4	Commercial (0°C to 70°C)
	AT17N010-10PC	8P3	
	AT17N010-10SC	20S2	
	AT17N010-10CI	8CN4	Industrial (-40°C to 85°C)
	AT17N010-10PI	8P3	
	AT17N010-10SI	20S2	
2-Mbit	AT17N002-10CC	8CN4	Commercial (0°C to 70°C)
	AT17N002-10SC	20S2	
	AT17N002-10TQC	44A	
	AT17N002-10CI	8CN4	Industrial (-40°C to 85°C)
	AT17N002-10SI	20S2	
	AT17N002-10TQI	44A	
4-Mbit	AT17N040-10TQC	44A	Commercial (0°C to 70°C)
	AT17N040-10TQI	44A	Industrial (-40°C to 85°C)

Notes: 1. The last-time buy is April 11, 2006 for the shaded parts.
2. For the -10CC and -10CI packages, customers may migrate to AT17LVXXX-10CU.

Packaging Information

8CN4 – LAP





COMMON DIMENSIONS
(Unit of Measure = mm)

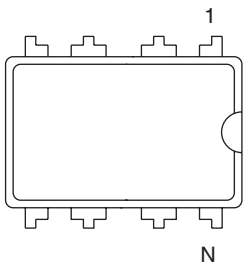
SYMBOL	MIN	NOM	MAX	NOTE
A	0.94	1.04	1.14	
A1	0.30	0.34	0.38	
b	0.45	0.50	0.55	1
D	5.89	5.99	6.09	
E	4.89	5.99	6.09	
e		1.27 BSC		
e1		1.10 REF		
L	0.95	1.00	1.05	1
L1	1.25	1.30	1.35	1

Note: 1. Metal Pad Dimensions.

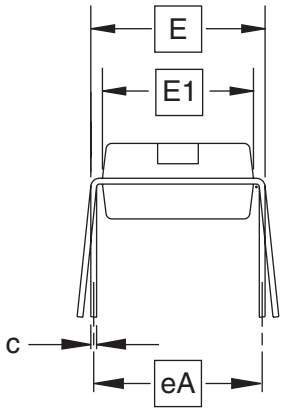
11/14/01

2325 Orchard Parkway San Jose, CA 95131	**TITLE** **8CN4**, 8-lead (6 x 6 x 1.04 mm Body), Lead Pitch 1.27 mm, Leadless Array Package (LAP)	**DRAWING NO.** 8CN4	**REV.** A

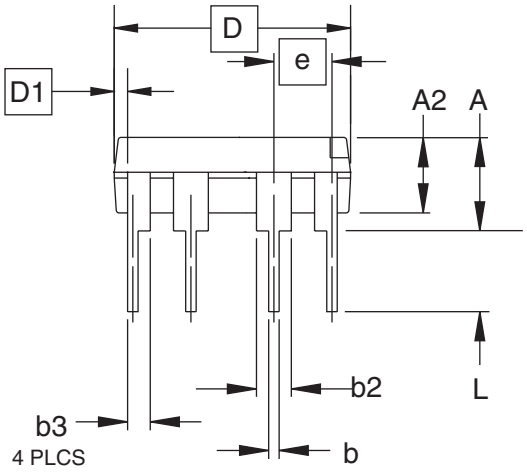
8P3 – PDIP



Top View



End View



Side View

COMMON DIMENSIONS
(Unit of Measure = inches)

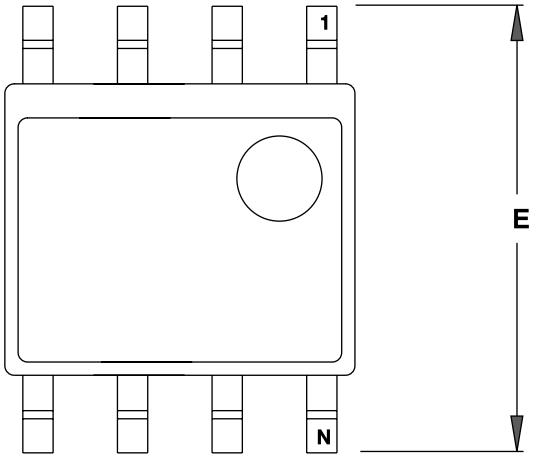
SYMBOL	MIN	NOM	MAX	NOTE
A			0.210	2
A2	0.115	0.130	0.195	
b	0.014	0.018	0.022	5
b2	0.045	0.060	0.070	6
b3	0.030	0.039	0.045	6
c	0.008	0.010	0.014	
D	0.355	0.365	0.400	3
D1	0.005			3
E	0.300	0.310	0.325	4
E1	0.240	0.250	0.280	3
e	0.100 BSC			
eA	0.300 BSC			4
L	0.115	0.130	0.150	2

Notes:
1. This drawing is for general information only; refer to JEDEC Drawing MS-001, Variation BA for additional information.
2. Dimensions A and L are measured with the package seated in JEDEC seating plane Gauge GS-3.
3. D, D1 and E1 dimensions do not include mold Flash or protrusions. Mold Flash or protrusions shall not exceed 0.010 inch.
4. E and eA measured with the leads constrained to be perpendicular to datum.
5. Pointed or rounded lead tips are preferred to ease insertion.
6. b2 and b3 maximum dimensions do not include Dambar protrusions. Dambar protrusions shall not exceed 0.010 (0.25 mm).

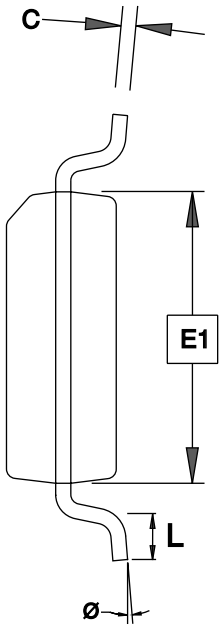
01/09/02

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	**8P3**, 8-lead, 0.300" Wide Body, Plastic Dual In-line Package (PDIP)	8P3	B

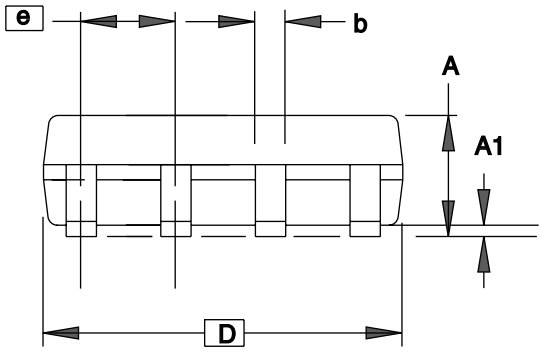
8S1 – SOIC



TOP VIEW



END VIEW



SIDE VIEW

COMMON DIMENSIONS
(Unit of Measure = mm)

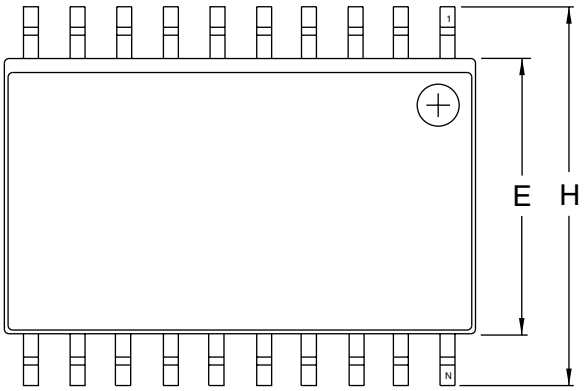
SYMBOL	MIN	NOM	MAX	NOTE
A	1.35	–	1.75	
A1	0.10	–	0.25	
b	0.31	–	0.51	
C	0.17	–	0.25	
D	4.80	–	5.05	
E1	3.81	–	3.99	
E	5.79	–	6.20	
e	1.27 BSC			
L	0.40	–	1.27	
θ	0°	–	8°	

Note: These drawings are for general information only. Refer to JEDEC Drawing MS-012, Variation AA for proper dimensions, tolerances, datums, etc.

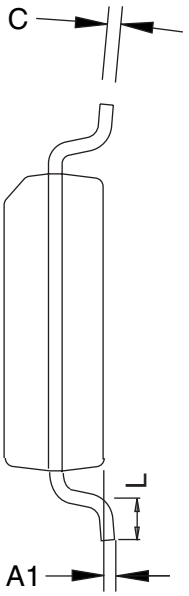
3/17/05

	TITLE	DRAWING NO.	REV.
1150 E. Cheyenne Mtn. Blvd. Colorado Springs, CO 80906	**8S1**, 8-lead (0.150" Wide Body), Plastic Gull Wing Small Outline (JEDEC SOIC)	8S1	C

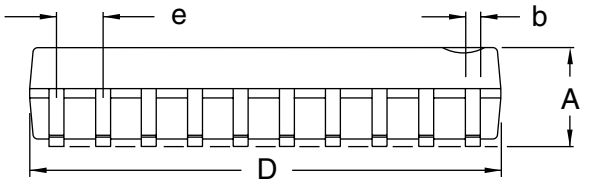
20S2 – SOIC



Top View



End View



Side View

COMMON DIMENSIONS
(Unit of Measure = inches)

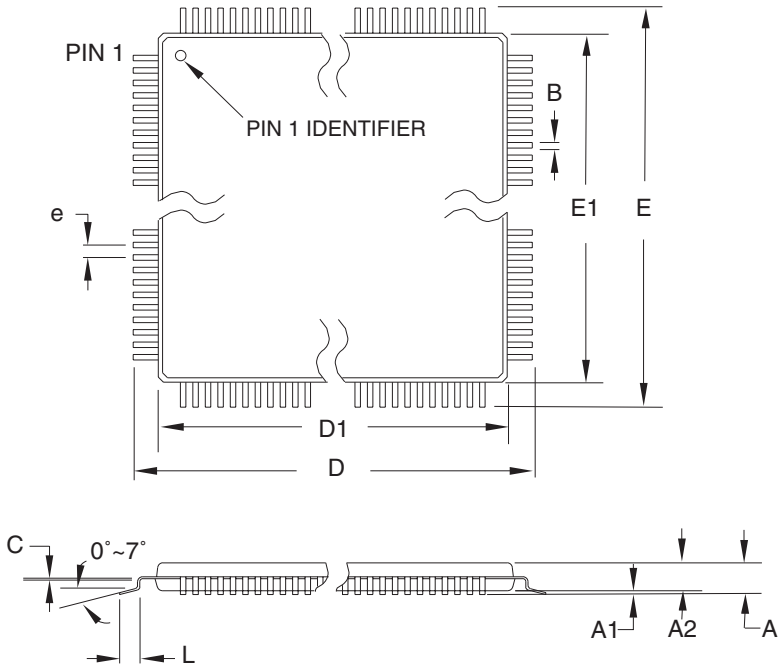
SYMBOL	MIN	NOM	MAX	NOTE
A	0.0926		0.1043	
A1	0.0040		0.0118	
b	0.0130		0.0200	4
C	0.0091		0.0125	
D	0.4961		0.5118	1
E	0.2914		0.2992	2
H	0.3940		0.4190	
L	0.0160		0.050	3
e	0.050 BSC			

Notes:
1. This drawing is for general information only; refer to JEDEC Drawing MS-013, Variation AC for additional information.
2. Dimension "D" does not include mold Flash, protrusions or gate burrs. Mold Flash, protrusions and gate burrs shall not exceed 0.15 mm (0.006") per side.
3. Dimension "E" does not include inter-lead Flash or protrusion. Inter-lead Flash and protrusions shall not exceed 0.25 mm (0.010") per side.
4. "L" is the length of the terminal for soldering to a substrate.
5. The lead width "b", as measured 0.36 mm (0.014") or greater above the seating plane, shall not exceed a maximum value of 0.61 mm (0.024") per side.

1/9/02

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	**20S2**, 20-lead, 0.300" Wide Body, Plastic Gull Wing Small Outline Package (SOIC)	20S2	A

44A – TQFP



COMMON DIMENSIONS
(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
A	–	–	1.20	
A1	0.05	–	0.15	
A2	0.95	1.00	1.05	
D	11.75	12.00	12.25	
D1	9.90	10.00	10.10	Note 2
E	11.75	12.00	12.25	
E1	9.90	10.00	10.10	Note 2
B	0.30	–	0.45	
C	0.09	–	0.20	
L	0.45	–	0.75	
e	0.80 TYP			

Notes:
1. This package conforms to JEDEC reference MS-026, Variation ACB.
2. Dimensions D1 and E1 do not include mold protrusion. Allowable protrusion is 0.25 mm per side. Dimensions D1 and E1 are maximum plastic body size dimensions including mold mismatch.
3. Lead coplanarity is 0.10 mm maximum.

10/5/2001

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	**44A,** 44-lead, 10 x 10 mm Body Size, 1.0 mm Body Thickness, 0.8 mm Lead Pitch, Thin Profile Plastic Quad Flat Package (TQFP)	44A	B

Revision History

Revision Level – Release Date	History
B – March 2006	Added last-time buy for AT17NXXX-10CC and AT17NXXX-10CI.

Atmel Corporation

2325 Orchard Parkway
San Jose, CA 95131, USA
Tel: 1(408) 441-0311
Fax: 1(408) 487-2600

Regional Headquarters

Europe

Atmel Sarl
Route des Arsenaux 41
Case Postale 80
CH-1705 Fribourg
Switzerland
Tel: (41) 26-426-5555
Fax: (41) 26-426-5500

Asia

Room 1219
Chinachem Golden Plaza
77 Mody Road Tsimshatsui
East Kowloon
Hong Kong
Tel: (852) 2721-9778
Fax: (852) 2722-1369

Japan

9F, Tonetsu Shinkawa Bldg.
1-24-8 Shinkawa
Chuo-ku, Tokyo 104-0033
Japan
Tel: (81) 3-3523-3551
Fax: (81) 3-3523-7581

Atmel Operations

Memory

2325 Orchard Parkway
San Jose, CA 95131, USA
Tel: 1(408) 441-0311
Fax: 1(408) 436-4314

Microcontrollers

2325 Orchard Parkway
San Jose, CA 95131, USA
Tel: 1(408) 441-0311
Fax: 1(408) 436-4314

La Chantrerie
BP 70602
44306 Nantes Cedex 3, France
Tel: (33) 2-40-18-18-18
Fax: (33) 2-40-18-19-60

ASIC/ASSP/Smart Cards

Zone Industrielle
13106 Rousset Cedex, France
Tel: (33) 4-42-53-60-00
Fax: (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd.
Colorado Springs, CO 80906, USA
Tel: 1(719) 576-3300
Fax: 1(719) 540-1759

Scottish Enterprise Technology Park
Maxwell Building
East Kilbride G75 0QR, Scotland
Tel: (44) 1355-803-000
Fax: (44) 1355-242-743

RF/Automotive

Theresienstrasse 2
Postfach 3535
74025 Heilbronn, Germany
Tel: (49) 71-31-67-0
Fax: (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd.
Colorado Springs, CO 80906, USA
Tel: 1(719) 576-3300
Fax: 1(719) 540-1759

Biometrics/Imaging/Hi-Rel MPU/
High Speed Converters/RF Datacom

Avenue de Rochepleine
BP 123
38521 Saint-Egreve Cedex, France
Tel: (33) 4-76-58-30-00
Fax: (33) 4-76-58-34-80

Literature Requests
www.atmel.com/literature

3020B–CNFG–03/06